Am27S19/27S19A Am27S19SA/27LS19

256-Bit (32x8) Bipolar PROM

DISTINCTIVE CHARACTERISTICS

- Ultra high speed
- Highly reliable, ultra-fast programming Platinum-Silicide fuses
- High-programming yield

- Low-current PNP inputs
- High-current open collector and three-state outputs
- Fast chip select
- **GENERAL DESCRIPTION**

The Am27S19 (32 words by 8 bits) is a Schottky TTL Programmable Read-Only Memory (PROM).

This device is available in three-state (Am27S19) output versions. These outputs are compatible with low-power Schottky bus standards capable of satisfying the requirements of a variety of microprogrammable controls, mapping functions, code conversions, or logic replacements. Easy word depth expansion is facilitated by an active LOW output enable (G).

This device is also available in a low-power version $\mbox{Am27LS19}.$



BLOCK DIAGRAM

PRODUCT SELECTOR GUIDE

Three-State Part Number	Am27	S195A	Am27	/S19A	Am2	7519	Am27	/LS19
Address Access Time	15 ns	20 ns	25 ns	35 ns	40 ns	50 ns	55 ns	70 ns
Operating Range	с	м	с	м	с	м	с	м



Advanced Micro Devices



Note: Pin 1 is marked for orientation.

*Also available in a 16-pin Flatpack. Pinout identical to DIPs.

**Also available in a 16-pin Plastic Leaded Chip Carrier. Pinout identical to LCC.





ORDERING INFORMATION

Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of: **a. Device Number**



- c. Package Type
- d. Temperature Range
- e. Optional Processing



Valid Cor	nbinations
AM27S19	PC, PCB,
AM27S19A	DC, DCB, FC, FCB,
AM27S19SA	LC, LCB,
AM27LS19	- JC, JCB

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.

MILITARY ORDERING INFORMATION

APL Products

AMD products for Aerospace and Defense applications are available in several packages and operating ranges. APL (Approved Products List) products are fully compliant with MIL-STD-883C requirements. The order number (Valid Combination) for APL products is formed by a combination of: **a. Device Number**



Group A tests consist of Subgroups 1, 2, 3, 7, 8, 9, 10, 11.

MILITARY BURN-IN

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Method 1015, Conditions A through E. Test conditions are selected at AMD's option.

PIN DESCRIPTION

A0-A4 Address Inputs

The 5-bit field presented at the address inputs selects one of 32 memory locations to be read from.

Q0-Q7 Data Output Port

The outputs whose state represents the data read from the selected memory locations

G Output Enable

Provides direct control of the Q output three-state buffers. Outputs disabled forces all open-collector outputs to an

FUNCTIONAL DESCRIPTION

The Am27S19 PROM may be used as a code converter. Examples include conversion of hexadecimal, octal of BCD to seven segment display drive format. In many code conversion applications an extra PROM address input is available and may be used as a polarity control, blanking control or code OFF state and all three-state outputs to a floating or highimpedance state.

Disable = G

V_{CC} Device Power Supply Pin

The most positive of the logic power supply pins.

GND Device Power Supply Pin

The most negative of the logic power supply pins.

selector input. The use of a single Am27S19 to convert the outputs of a binary counter to either excess three or gray code format is illustrated below. In this case both codes are generated in true and complemented form simultaneously.

TRUTH TABLE



		UE	TR		ENT	EN	MPL	co		E\$8	DRI	AD	
	G 0	Q1	Q2	Q3	Q.	Q ₅	0	07	A ₀	A1	Az	A3	A4
	1	1	0	0	0	0	1	1	0	0	0	0	0
	0	0	1	0	1	1	0	1	1	0	0	0	0
_	1	0	1	0	0	1	0	1	0	1	0	0	0
8	0	1	1	0	1	0	0	1	1	1	0	0	0
2	1	1	1	0	0	0	0	1	0	0	1	0	0
DXCE88	0	0	0	1	1	1	1	0	1	0	1	0	0
-	1	0	0	1	0	1	1	0	0	1	1	0	0
Ŧ	0	1	0	1	1	0	1	0	1	1	1	0	0
THREE CODE	1	1	0	1	0	0	1	0	0	0	0	1	0
M	0	0	1	1	1	1	0	0	1	0	0	1	0
8	X	X	X	X	X	X	X	X	0	1	0	1	0
ĕ	X	X	X	X	X	X	X	X	1	1	0	1	0
	X	X	Х	X	X	X	X	X	0	0	1	1	0
	X	X	X	X	X	X	X	X	1	0	1	1	0
	X	X	X	X	X	X	X	X	0	1	1	1	0
	X	X	X	X	X	X	X	X	1	1	1	1	0
	0	0	0	0	1	1	1	1	0	0	0	0	1
	1	0	0	0	0	1	1	1	1	0	0	0	1
	1	1	0	0	0	0	1	1	0	1	0	0	1
	0	1	0	0	1	0	1	1	1	1	0	0	1
	0	1	1	0	1	0	0	1	0	0	1	0	1
Q	1		1	0	0	0	0	1	1	0	1	0	1
3	1	0	1	0	0	1	0	1	0	1	1	0	1
GRAY CODE			1	1	1	1	0	6	1	1	1	0	1
8	0	0	1	1	0	1	0	ŏ		0	0	1	1
ŏ	1	1	1	1	ŏ	0	0	Ö	1	1	0	1	1
10	0	1	1	1	1	ŏ	ő	ŏ	0 1	1	-	1	1
	õ	1	0	1	1	0	1	ŏ	0	0	0	1	1
	1	1	ŏ	1	6	ŏ	1	ŏ	1	ŏ	1	1	1
	1	0	ŏ	1	0	1	+	ŏ	0	1	1	1	1
	ò	ŏ	ŏ	÷	1	1	1	ŏ	1	1	1		1

ABSOLUTE MAXIMUM RATINGS

Storage Temperature 65 to + 150°C
Ambient Temperature with
Power Applied 55 to + 125°C
Supply Voltage 0.5 V to +7.0 V
DC Voltage Applied to Outputs
(Except During Programming) 0.5 to + V _{CC} Max.
DC Voltage Applied to Outputs
During Programming 21 V
Output Current into Outputs During
Programming (Max. Duration of 1 sec.)
DC Input Voltage0.5 V to 5.5 V
DC Input Current 30 to +5 mA

Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

OPERATING	RANGES
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Commercial (C) Devices Ambient Temperature (T _A)0 to +75°C Supply Voltage (V _{CC})+4.75 V to +5.25 V
Military (M) Devices* Case Temperature (T _C)
Operation reason define these limits between which the

Operating ranges define those limits between which the functionality of the device is guaranteed.

*Military products 100% tested at $T_C = +25^{\circ}C$, +125°C, and -55°C.

DC CHARACTERISTICS over operating ranges u	inless otherwise specified (for APL Products, Group A,
Subgroups 1, 2, 3 are tested unless otherwise noted	d)

Parameter Symbol	Parameter Description	Test Conditio	ins	Min.	Тур.	Max.	Unit
VOH (Note 1)	Output HIGH Voltage	V _{CC} = Min., I _{OH} = -2.0 mA V _{IN} = V _{IH} or V _{IL}	2.4			v	
VOL	Output LOW Voltage	$V_{CC} = Min., I_{OL} = 16 \text{ mA}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$			0.45	v	
VIH	Input HIGH Level	Guaranteed input logical HIG voltage for all inputs (Note 2	2.0			v	
ViL	Input LOW Level	Guaranteed input logical LO voltage for all inputs (Note 2			0.8	v	
111_	Input LOW Current	V _{CC} = Max., V _{IN} = 0.45 V				-0.250	mA
lini	Input HIGH Current	V _{CC} = Max., V _{IN} = 2.7 V				25	μA
ISC (Note 1)	Output Short-Circuit Current	V _{CC} = Max., V _{OUT} = 0.0 V (I	Note 3)	-20		-90	mA
		All inputs = GND,	27S Devices			115	mA
lcc	Power Supply Current	V _{CC} = Max.	27LS Devices			80	
VI	Input Clamp Voltage	V _{CC} = Min., I _{IN} = -18 mA			1	-1.2	v
		Vcc = Max. (Alete 1)	Vo = Vcc			40	
CEX	Output Leakage Current	$V_{\overline{G}} = 2.4 V$ (Note 1)	V _O = 0.4 V			- 40	μA
CiN	Input Capacitance	V _{CC} = 5.00 V., T _A = 25°C			4		pF
COUT	Output Capacitance	VIN/VOUT = 2.0 V. @ f = 1	MHz (Note 4)		8		pr-

Notes: 1. This applies to three-state devices only.

2. VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.

without suitable equipment. 3. Not more than one output should be shorted at a time. Duration of the short circuit should not be more than one second. 4. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

SWITCHING CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 9, 10, 11 are tested unless otherwise noted*)

				COM'L		MIL		
No.	Parameter Symbol		Version	Min.	Max.	Min.	Max.	Unit
			SA		15		20	
		A		25		35	1	
1 TAVQV Address Valid to Output Valid Access	Address valid to Output valid Access Time	STD		40		50	ns	
			LS		55		70	1
		Delay from Output Enable Valid to Output Hi-Z	SA		13		20	ns
	70107		A		20		25	
2	TGVQZ		STD		25		30	
			LS		40		50	1
			SA		13		20	
3 TGVQV Del		A		20		25	1	
	Delay from Output Enable Valid to Output Valid	STD		25		30	ns	
			LS		40		50	1

See also Switching Test Circuits.

Notes: 1. Tests are performed with input transition time of 5 ns or less, timing reference levels of 1.5 V, and input pulse levels of 0 to 3.0 V using test load in A under Switching Test Circuits.
2. TGVQZ is measured at steady state HIGH output voltage -0.5 V and steady state LOW output voltage +0.5 V output levels using the test load in B under Switching Test Circuits.

*Subgroups 7 and 8 apply to functional tests.





A. Output Load for all tests except TGVQZ **B.** Output Load for TGVQZ

Notes: 1. All device test loads should be located within 2" of device output pin.

S₁ is open for Output Data HIGH to Hi-Z and Hi-Z to Output Data HIGH tests. S₁ is closed for all other AC tests.

3. Load capacitance includes all stray and fixture capacitance.

SWITCHING WAVEFORMS

KEY TO SWITCHING WAVEFORMS



